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SCES596F - JULY 2004-REVISED MAY 2010

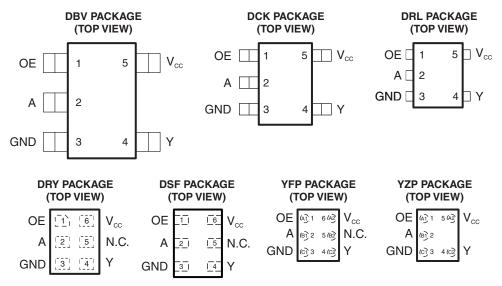
LOW-POWER SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

Check for Samples: SN74AUP1G126

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Max)
- Low Dynamic-Power Consumption (C_{pd} = 4 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typ)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- Input-Disable Feature Allows Floating Input Conditions
- I_{off} Supports Partial-Power-Down Mode Operation

- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $t_{pd} = 4.6 \text{ ns Max at } 3.3 \text{ V}$
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22-
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)



N.C. - No internal connection.

See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static and dynamic power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity (see Figure 1 and Figure 2).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



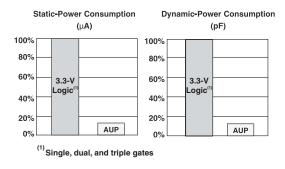


Figure 1. AUP – The Lowest-Power Family

Figure 2. Excellent Signal Integrity

This bus buffer gate is a single line driver with a 3-state output. The output is disabled when the output-enable (OE) input is low. This device has the input-disable feature, which allows floating input signals.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

NanoStar[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION(1)

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP	Reel of 3000	SN74AUP1G126YFPR	HN _
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G126YZPR	HN _
	QFN – DRY	Reel of 5000	SN74AUP1G126DRYR	HN
–40°C to 85°C	μQFN – DSF	Reel of 5000	SN74AUP1G126DSFR	HN
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1G126DBVR	H26
	301 (301-23) – DBV	Reel of 250	SN74AUP1G126DBVT	П20_
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP1G126DCKR	HN
	301 (30-70) - DCK	Reel of 250	SN74AUP1G126DCKT	HIN_
	SOT (SOT-553) – DRL	Reel of 4000	SN74AUP1G126DRLR	HN_

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

FUNCTION TABLE

INP	OUTPUT	
OE	Α	Υ
Н	Н	Н
Н	L	L
L	X ⁽¹⁾	Z

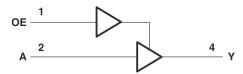
(1) Floating inputs allowed

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³⁾ DBV/DCK/DRL: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YZP/YZT: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

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LOGIC DIAGRAM (POSITIVE LOGIC)





ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range (2)		-0.5	4.6	V
Vo	Voltage range applied to any output in the high-imped	ance or power-off state(2)	-0.5	4.6	V
Vo	Output voltage range in the high or low state ⁽²⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current		±20	mA	
	Continuous current through V _{CC} or GND		±50	mA	
		DBV package		206	
		DCK package		252	
0	Declare the small in a colonia (3)	DRL package		142	9 0 AA7
θ_{JA}	Package thermal impedance (3)	DSF package		TBD	°C/W
		DRY package		234	
		YFP/YZP/YZT package		132	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

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RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		0.8	3.6	V	
		V _{CC} = 0.8 V	V _{CC}	3.6		
.,	High level inner voltage	V _{CC} = 1.1 V to 1.95 V	0.65 × V _{CC}	3.6		
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.6	3.6	V	
		V _{CC} = 3 V to 3.6 V	2	3.6		
		V _{CC} = 0.8 V		0		
.,	Lavy lavyal import orality ma	V _{CC} = 1.1 V to 1.95 V	0	0.35 × V _{CC}	V	
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	0.7	V	
		V _{CC} = 3 V to 3.6 V	0	0.9		
.,	Output valtage	Active state	0	V _{CC}	V	
V _O	Output voltage	3-state	0	3.6	V	
		V _{CC} = 0.8 V		-20	μА	
		V _{CC} = 1.1 V		-1.1		
	High level output ourrent	V _{CC} = 1.4 V		-1.7		
Іон	High-level output current	V _{CC} = 1.65 V		-1.9	mA	
		V _{CC} = 2.3 V		-3.1		
		V _{CC} = 3 V		-4		
		V _{CC} = 0.8 V		20	μΑ	
		V _{CC} = 1.1 V		1.1		
	Low-level output current	V _{CC} = 1.4 V		1.7		
l _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9		
		$V_{CC} = 2.3 \text{ V}$				
		V _{CC} = 3 V		4		
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$		200	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow of Floating CMOS Inputs, literature number SCBA004.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

DAE	AMETED	TEST COMPITIONS	V	T,	_A = 25°C	$T_A = -40^{\circ}C$	to 85°C	UNIT	
PAR	RAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP MAX	MIN	MAX	UNII	
		I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1			
		I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		0.7 × V _{CC}			
		$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11		1.03			
V		I _{OH} = −1.9 mA	1.65 V	1.32		1.3		V	
V_{OL}		$I_{OH} = -2.3 \text{ mA}$	2.3 V	2.05		1.97		V	
		$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9		1.85			
		$I_{OH} = -2.7 \text{ mA}$	3 V	2.72		2.67			
		$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55			
		$I_{OL} = 20 \mu A$	0.8 V to 3.6 V		0.1		0.1		
		I _{OL} = 1.1 mA	1.1 V		$0.3 \times V_{CC}$		0.3 × V _{CC}		
		$I_{OL} = 1.7 \text{ mA}$	1.4 V		0.31		0.37		
V _{OL}		$I_{OL} = 1.9 \text{ mA}$	1.65 V		0.31		0.35	V	
		$I_{OL} = 2.3 \text{ mA}$	221/		0.31		0.33	v	
		$I_{OL} = 3.1 \text{ mA}$	2.3 V		0.44		0.45		
		$I_{OL} = 2.7 \text{ mA}$	3 V		0.31		0.33	1	
		$I_{OL} = 4 \text{ mA}$	3 V		0.44	0.45			
l _l	A or OE input	$V_I = GND \text{ to } 3.6 \text{ V}$	0 V to 3.6 V		0.1		0.5	μΑ	
I_{off}		V_I or $V_O = 0 V$ to 3.6 V	0 V		0.2		0.6	μΑ	
ΔI_{off}		V_I or $V_O = 0$ V to 3.6 V	0 V to 0.2 V		0.2		0.6	μΑ	
I_{OZ}		$V_O = V_{CC}$ or GND	3.6 V				0.5	μΑ	
I _{CC}		$V_I = GND$ or $(V_{CC}$ to 3.6 V), OE = GND, $I_O = 0$	0.8 V to 3.6 V		0.5		0.9	μА	
	A input	$V_1 = V_{CC} - 0.6 V^{(1)}$	227		40		50		
ΔI _{CC}	OE input	I _O = 0	3.3 V		110		120	μΑ	
All inputs		$V_I = GND \text{ to } 3.6 \text{ V},$ $OE = V_{CC}^{(2)}$	0.8 V to 3.6 V		0		0	μ	
_			0 V		1.5			pF	
Ci		$V_I = V_{CC}$ or GND 3.6 V	3.6 V		1.5				
C _o		$V_O = V_{CC}$ or GND	3.6 V		3			pF	

 $[\]begin{array}{ll} \hbox{(1)} & \hbox{One input at $V_{CC}-0.6$ V, other input at V_{CC} or GND} \\ \hbox{(2)} & \hbox{To show I_{CC} is very low when the input-disable feature is enabled} \end{array}$

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 pF$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V _{cc}	$T_A = 25^{\circ}C$			T _A = -40°C to 85°C		UNIT					
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX						
			0.8 V		18.1									
			1.2 V ± 0.1 V	4.3	7.4	12.6	2.7	15.3						
	٨		1.5 V ± 0.1 V	3.3	5.2	8.5	1	10.2						
t _{pd}	Α	Y	1.8 V ± 0.15 V	2.6	4.1	6.8	1.3	8.3	ns					
			2.5 V ± 0.2 V	2	2.9	4.7	1.1	5.8						
			3.3 V ± 0.3 V	1.7	2.4	3.8	1	4.6						
								0.8 V		19.1				
		Y	1.2 V ± 0.1 V	5.1	9.3	15.9	3.6	19.2	20					
	OF		1.5 V ± 0.1 V	4.1	6.6	10.5	2.5	12.7						
t _{en}	OE		1.8 V ± 0.15 V	3.2	5.3	8.7	2.1	10.3	ns					
			2.5 V ± 0.2 V	2.5	3.8	6	1.6	7.2						
			3.3 V ± 0.3 V	2.1	3.2	4.9	1.4	5.9						
			0.8 V		12.1									
			1.2 V ± 0.1 V	2.4	4.1	6.9	2.2	7.7						
	OF	V	1.5 V ± 0.1 V	1.8	2.9	4.5	1.7	5.1						
t _{dis}	OE	OE Y	1.8 V ± 0.15 V	1	2.9	4.3	1.5	4.7	ns					
			2.5 V ± 0.2 V	1	1.8	2.7	1	3.3						
			3.3 V ± 0.3 V	1.2	2.2	3.2	1.1	4						



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	Т,	_{\(\)} = 25°C		T _A = -4 to 85		UNIT		
	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX			
					0.8 V		20.5	13.7			
			1.2 V ± 0.1 V	4.6	8.4	9.3	3.6	16.6			
	A or D	V	1.5 V ± 0.1 V	3.5	5.9	7.5	2.4	11.1			
t _{pd}	A or B	Y	1.8 V ± 0.15 V	3.9	4.7	5.3	1.3	9.1	ns		
			2.5 V ± 0.2 V	2.3	3.4	4.3	1.6	6.4			
			3.3 V ± 0.3 V	2.1	2.8		1.4	5.2			
					0.8 V		21.8	16.8			
		Y	1.2 V ± 0.1 V	4.9	10.2	11.2	4.4	20.2	ns		
	OE		1.5 V ± 0.1 V	3.9	7.3	9.2	3.3	13.5			
t _{en}	OE		1.8 V ± 0.15 V	3.4	5.8	6.4	2.7	11			
			2.5 V ± 0.2 V	2.5	4.3	5.4	2.1	7.8			
			3.3 V ± 0.3 V	2.1	3.7		1.9	6.4			
			0.8 V		13						
			1.2 V ± 0.1 V	3.8	6.6	11.7	1.2	14			
	OE	Y	1.5 V ± 0.1 V	2.2	4.7	7.9	1.3	9.3	ns		
t _{dis}	OE	OE Y	1.8 V ± 0.15 V	2.4	4.4	6.4	2.2	7.5			
			2.5 V ± 0.2 V	1.3	3.1	4.9	1.2	5.4			
			3.3 V ± 0.3 V	1.9	3.4	5	1.9	5.6			

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	T,	λ = 25°C		T _A = -40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
			0.8 V		22.5				
			1.2 V ± 0.1 V	5.8	9.3	15.1	4.3	17.9	
	A D	Y	1.5 V ± 0.1 V	4.4	6.6	10.2	3	12.1	
t _{pd}	A or B	Y	1.8 V ± 0.15 V	3.5	5.3	8.3	2.3	9.9	ns
			2.5 V ± 0.2 V	2.7	3.9	5.8	1.9	7	
			3.3 V ± 0.3 V	2.4	3.2	4.7	1.8	5.7	
		Y	0.8 V		25.2				ns
			1.2 V ± 0.1 V	7	11.3	18.1	5.4	21.4	
	OE		1.5 V ± 0.1 V	5.5	8.1	12.2	4.1	14.5	
t _{en}			1.8 V ± 0.15 V	4.3	6.5	10.1	3.3	12	
			2.5 V ± 0.2 V	3.4	4.8	7.1	2.6	8.4	
			3.3 V ± 0.3 V	2.9	4.1	5.9	2.3	6.9	
			0.8 V		14				
			1.2 V ± 0.1 V	3.7	5.8	8.2	3.3	11	
	OF	V	1.5 V ± 0.1 V	5.5	3.9	5.9	2.1	8	ns
t _{dis}	OE	Y	1.8 V ± 0.15 V	3.3	4.5	6.6	2.9	7.4	
			2.5 V ± 0.2 V	2.3	3.2	4.3	1.8	5.1	
			3.3 V ± 0.3 V	2.4	4.8	6.2	3.1	6.7	

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V _{CC}	Т,	_A = 25°C		T _A = -40°C to 85°C		UNIT
	(INPUT)			MIN	TYP	MAX	MIN	MAX	
			0.8 V		29				
			1.2 V ± 0.1 V	7.4	12	18.7	6.6	21.4	
	A or D	Y	1.5 V ± 0.1 V	5.7	8.6	12.5	4.9	14.7	20
t _{pd}	A or B	r	1.8 V ± 0.15 V	4.8	6.9	10.1	3.1	12	ns
			2.5 V ± 0.2 V	3.9	5.1	7.2	3.3	8.7	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	3.5	4.8	6	3	7	
	OE		0.8 V		33.4				ns
		Y	1.2 V ± 0.1 V	8.8	14.1	21.8	7.4	25.5	
			1.5 V ± 0.1 V	6.9	10.1	14.6	5.6	17.4	
t _{en}			1.8 V ± 0.15 V	5.6	8.1	12	4.7	14.1	
			2.5 V ± 0.2 V	4.3	6.1	8.5	3.8	10	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	3.7	5.2	7.1	3.4	8.3	
			0.8 V		17.7				
			1.2 V ± 0.1 V	5.8	10	16	3.7	16	
+	OE	Y	1.5 V ± 0.1 V	5.7	7.7	10.9	1	10.7	ns
t _{dis}	OE .	OE Y	1.8 V ± 0.15 V	4.5	7.7	9.8	4.4	12.5	
			2.5 V ± 0.2 V	3.9	5.6	7.4	3.2	9	
			3.3 V ± 0.3 V	3.3	8.4	10.7	6.6	10.8	

OPERATING CHARACTERISTICS

 $T_{\Lambda} = 25^{\circ}C$

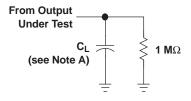
	PARAMETER		TEST CONDITIONS	V _{CC}	TYP	UNIT
				0.8 V	3.8	
				1.2 V ± 0.1 V	3.7	
		Outrote analysis	f 40 MH	1.5 V ±0.1 V	3.7	
	Outputs enabled	f = 10 MHz	1.8 V ± 0.15 V	3.7		
				2.5 V ± 0.2 V	3.9	
				3.3 V ± 0.3 V	4	
C_{pd}	Power dissipation capacitance			0.8 V	0	pF
	capacitarice			1.2 V ± 0.1 V	0	
				1.5 V ±0.1 V	0	
		Outputs disable	f = 10 MHz	1.8 V ± 0.15 V	0	
				2.5 V ± 0.2 V	0	
				2.5 V ± 0.2 V	0	
				3.3 V ± 0.3 V	0	

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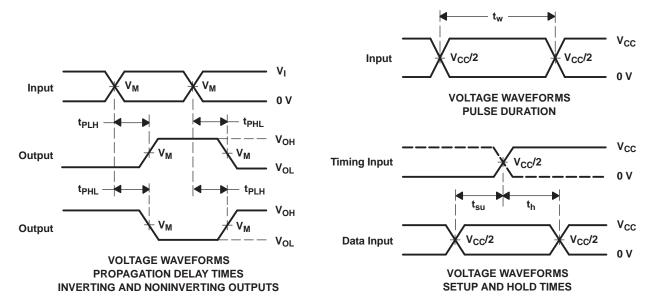
PARAMETER MEASUREMENT INFORMATION

(Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L V _M	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}



NOTES: A. C_L includes probe and jig capacitance.

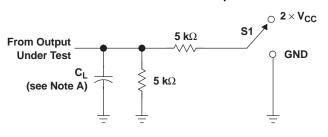
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r/t_f = 3 \text{ ns}$.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION (continued)

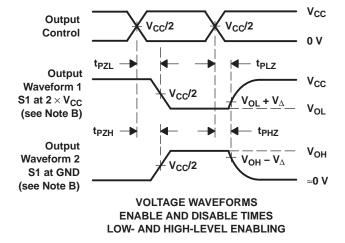
(Enable and Disable Times)



TEST	S 1
t _{PLZ} /t _{PZL}	2×V _{CC}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V_{CC} = 1.8 V \pm 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V_{CC} = 3.3 V \pm 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _∆	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_r/t_f = 3~ns$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

Submit Documentation Feedback

19-Nov-2010

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
74AUP1G126DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
74AUP1G126DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
74AUP1G126DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
74AUP1G126DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
74AUP1G126DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
74AUP1G126DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
74AUP1G126DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
74AUP1G126DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
74AUP1G126DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
SN74AUP1G126DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
SN74AUP1G126DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
SN74AUP1G126DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
SN74AUP1G126DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
SN74AUP1G126DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
SN74AUP1G126DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	Request Free Samples
SN74AUP1G126DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
SN74AUP1G126YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	Purchase Samples



PACKAGE OPTION ADDENDUM

19-Nov-2010

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74AUP1G126YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	Request Free Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G126DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G126DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G126DCKR	SC70	DCK	5	3000	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G126DCKT	SC70	DCK	5	250	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G126DRLR	SOT	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G126DRYR	SON	DRY	6	5000	180.0	8.4	1.25	1.6	0.7	4.0	8.0	Q1
SN74AUP1G126DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q2
SN74AUP1G126YFPR	DSBGA	YFP	6	3000	180.0	8.4	0.89	1.29	0.62	4.0	8.0	Q1
SN74AUP1G126YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1
SN74AUP1G126YZPR	DSBGA	YZP	5	3000	180.0	8.4	1.02	1.52	0.63	4.0	8.0	Q1

www.ti.com 6-May-2011



*All dimensions are nominal

7 III GITTIONOI OTO GITO TIONIII IGI							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G126DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G126DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G126DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G126DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G126DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G126DRYR	SON	DRY	6	5000	202.0	201.0	28.0
SN74AUP1G126DSFR	SON	DSF	6	5000	202.0	201.0	28.0
SN74AUP1G126YFPR	DSBGA	YFP	6	3000	220.0	220.0	34.0
SN74AUP1G126YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0
SN74AUP1G126YZPR	DSBGA	YZP	5	3000	220.0	220.0	34.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE

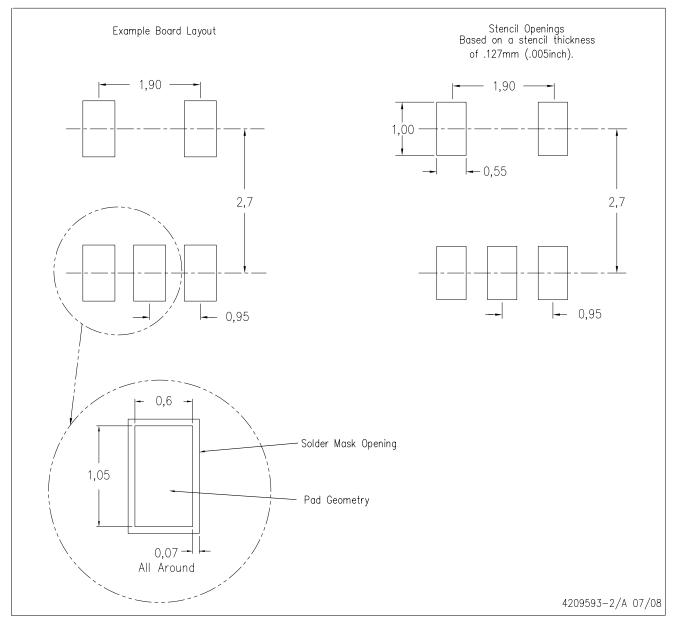


NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



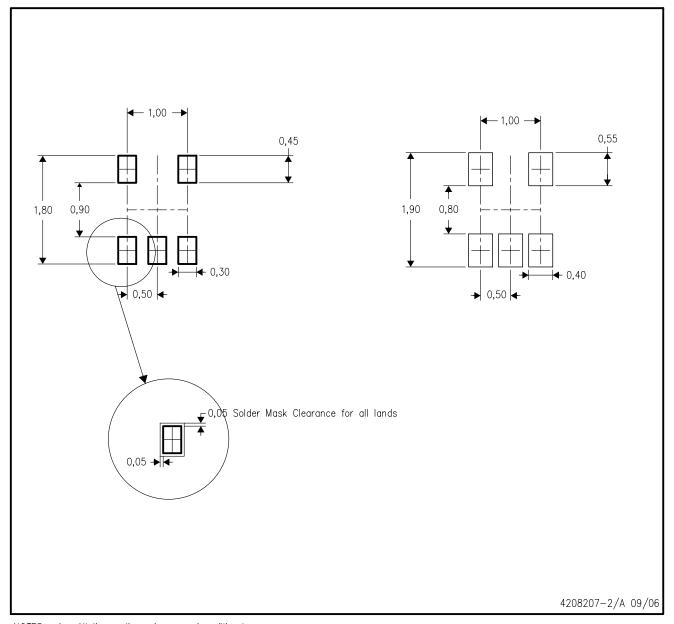
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



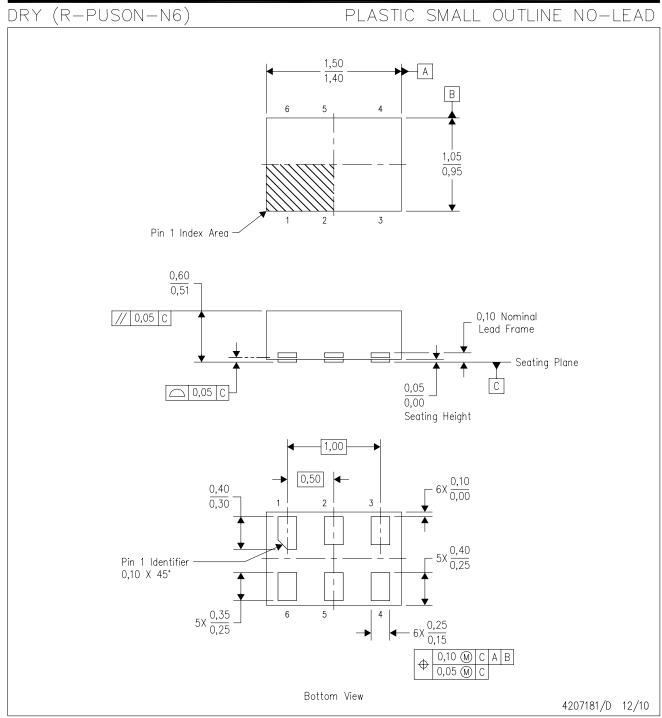
DRL (R-PDSO-N5)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





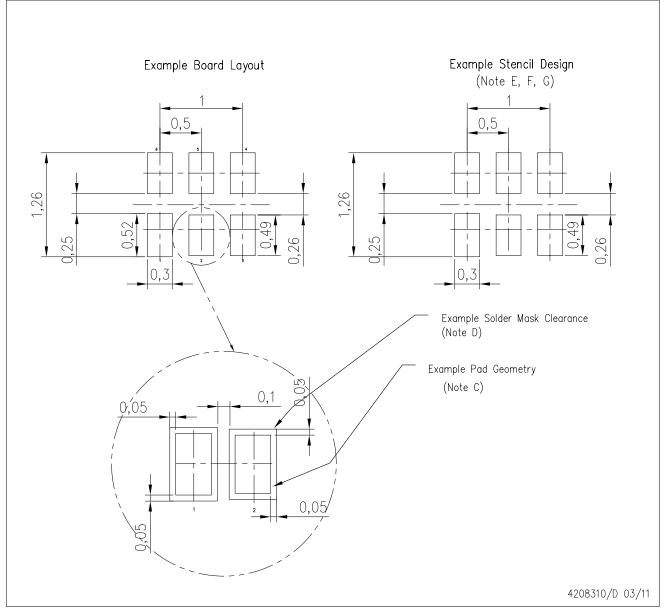
NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- D. This package complies to JEDEC MO-287 variation UFAD.



DRY (S-PUSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
 - E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
 - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





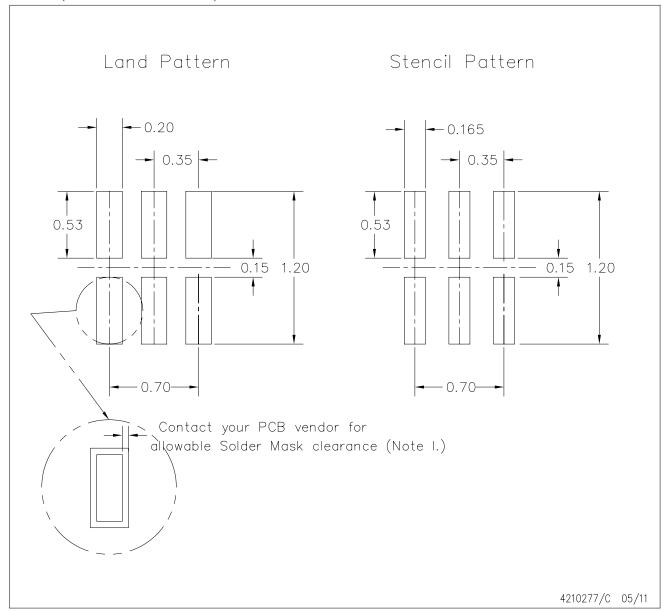
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
 C. SON (Small Outline No-Lead) package configuration.
 D. This package complies to JEDEC MO-287 variation X2AAF.



DSF(S-PX2SON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



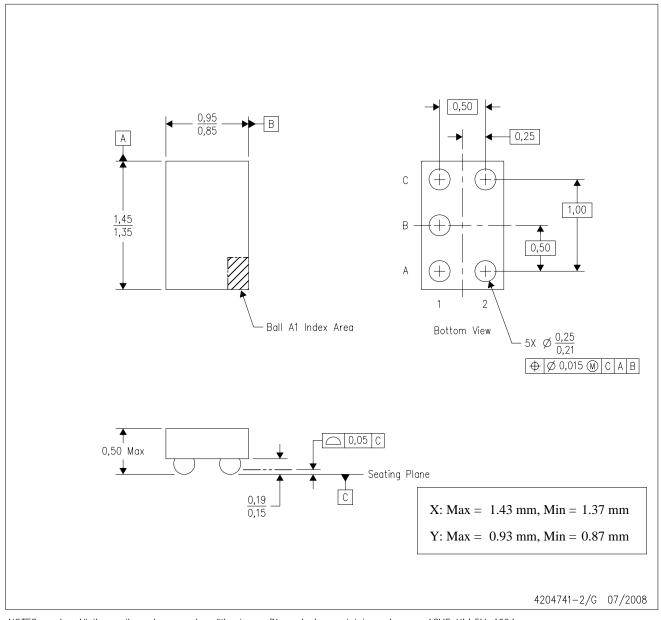
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Over—printing land for acceptable area ratio is not viable due to land width and bridging potential. Customer may further reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.
- H. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- I. Component placement force should be minimized to prevent excessive paste block deformation.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

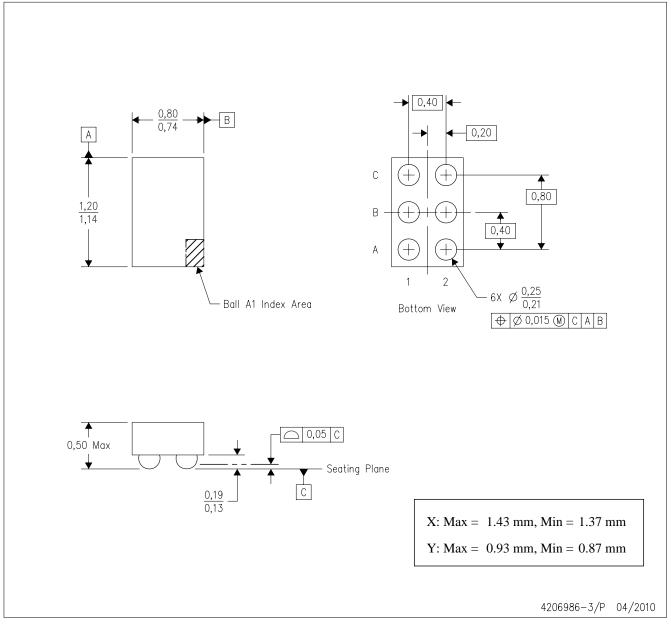
- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

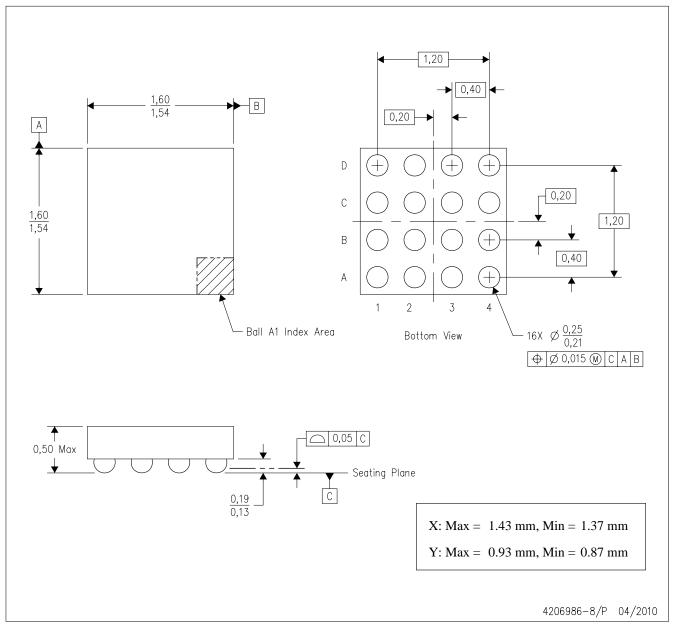
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a Pb-free solder ball design.

NanoFree is a trademark of Texas Instruments.



YFP (S-XBGA-N16)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a Pb-free solder ball design.

NanoFree is a trademark of Texas Instruments.



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DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
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Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
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